

LMV1012 Analog Series: Pre-Amplified IC's for High Gain 2-Wire Microphones

Check for Samples: [LMV1012](#)

FEATURES

- (Typical LMV1012-15, 2.2V supply, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, $V_{IN} = 18\text{ mV}_{PP}$, unless otherwise specified)
- Supply voltage
 - 2V - 5V
- Supply current
 - <180 μA
- Signal to noise ratio (A-weighted)
 - 60 dB
- Output voltage noise (A-weighted)
 - -89 dBV
- Total harmonic distortion
 - 0.09%
- Voltage gain
 - LMV1012-07
 - 7.8 dB

- LMV1012-15
 - 15.6 dB
- LMV1012-20
 - 20.9 dB
- LMV1012-25
 - 23.8 dB
- Temperature range
 - -40°C to 85°C
- Offered in 4-bump micro SMD packages

APPLICATIONS

- Cellular phones
- Headsets
- Mobile communications
- Automotive accessories
- PDAs
- Accessory microphone products

DESCRIPTION

The LMV1012 is an audio amplifier series for small form factor electret microphones. This 2-wire portfolio is designed to replace the JFET amplifier currently being used. The LMV1012 series is ideally suited for applications requiring high signal integrity in the presence of ambient or RF noise, such as in cellular communications. The LMV1012 audio amplifiers are guaranteed to operate over a 2.2V to 5.0V supply voltage range with fixed gains of 7.8 dB, 15.6 dB, 20.9 dB, and 23.8 dB. The devices offer excellent THD, gain accuracy and temperature stability as compared to a JFET microphone.

The LMV1012 series enables a two-pin electret microphone solution, which provides direct pin-to-pin compatibility with the existing JFET market.

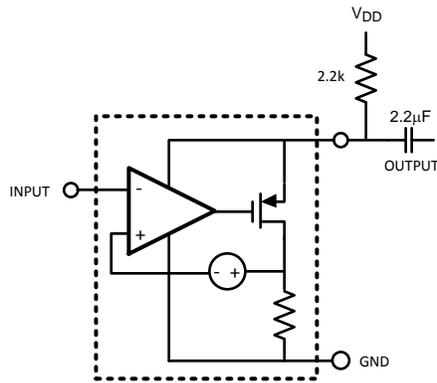
The devices are offered in extremely thin space saving 4-bump micro SMD packages. The LMV1012XP is designed for 1.0 mm canisters and thicker ECM canisters. These extremely miniature packages are designed for electret condenser microphones (ECM) form factor.



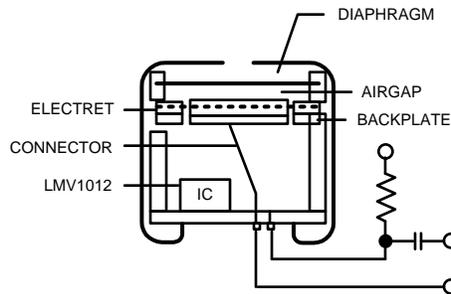
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Schematic Diagram



Built-In Gain Electret Microphone



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings ⁽¹⁾

ESD Tolerance ⁽²⁾	
Human Body Model	2500V
Machine Model	250V
Supply Voltage	
V _{DD} - GND	5.5V
Storage Temperature Range	-65°C to 150°C
Junction Temperature ⁽³⁾	150°C max
Mounting Temperature	
Infrared or Convection (20 sec.)	235°C

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

(2) Human Body Model (HBM) is 1.5 kΩ in series with 100 pF.

(3) The maximum power dissipation is a function of T_{J(MAX)}, θ_{JA} and T_A. The maximum allowable power dissipation at any ambient temperature is P_D = (T_{J(MAX)} - T_A)/θ_{JA}. All numbers apply for packages soldered directly into a PC board.

Operating Ratings ⁽¹⁾

Supply Voltage	2V to 5V
Temperature Range	-40°C to 85°C

(1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but specific performance is not guaranteed. For guaranteed specifications and the test conditions, see the Electrical Characteristics.

2.2V Electrical Characteristics ⁽¹⁾

Unless otherwise specified, all limits guaranteed for $T_J = 25^\circ\text{C}$, $V_{DD} = 2.2\text{V}$, $V_{IN} = 18\text{ mV}$, $R_L = 2.2\text{ k}\Omega$ and $C = 2.2\text{ }\mu\text{F}$.

Boldface limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min ⁽²⁾	Typ ⁽³⁾	Max ⁽²⁾	Units	
I_{DD}	Supply Current	$V_{IN} = \text{GND}$	LMV1012-07		139	250 300	μA
			LMV1012-15		180	300 325	
			LMV1012-20		160	250 300	
			LMV1012-25		141	250 300	
SNR	Signal to Noise Ratio	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$, A-Weighted	LMV1012-07		59		dB
			LMV1012-15		60		
			LMV1012-20		61		
			LMV1012-25		61		
V_{IN}	Max Input Signal	$f = 1\text{ kHz}$ and THD+N < 1%	LMV1012-07		170		mV_{PP}
			LMV1012-15		100		
			LMV1012-20		50		
			LMV1012-25		28		
V_{OUT}	Output Voltage	$V_{IN} = \text{GND}$	LMV1012-07	1.65 1.54	1.90	2.03 2.09	V
			LMV1012-15	1.54 1.48	1.81	1.94 2.00	
			LMV1012-20	1.65 1.55	1.85	2.03 2.13	
			LMV1012-25	1.65 1.49	1.90	2.02 2.18	
f_{LOW}	Lower -3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$		65		Hz	
f_{HIGH}	Upper -3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$		95		kHz	
e_n	Output Noise	A-Weighted	LMV1012-07		-96		dBV
			LMV1012-15		-89		
			LMV1012-20		-84		
			LMV1012-25		-82		
THD	Total Harmonic Distortion	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$	LMV1012-07		0.10		%
			LMV1012-15		0.09		
			LMV1012-20		0.12		
			LMV1012-25		0.15		
C_{IN}	Input Capacitance			2		pF	
Z_{IN}	Input Impedance			>1000		G Ω	
A_V	Gain	$f = 1\text{ kHz}$, $R_{SOURCE} = 50\Omega$	LMV1012-07	6.4 5.5	7.8	9.5 10.0	dB
			LMV1012-15	14.0 13.1	15.6	16.9 17.5	
			LMV1012-20	19.5 17.4	20.9	22.0 23.3	
			LMV1012-25	22.5 21.4	23.8	25.0 25.7	

(1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.

(2) All limits are guaranteed by design or statistical analysis.

(3) Typical values represent the most likely parametric norm.

5V Electrical Characteristics ⁽¹⁾

Unless otherwise specified, all limits guaranteed for $T_J = 25^\circ\text{C}$, $V_{DD} = 5\text{V}$, $V_{IN} = 18\text{ mV}$, $R_L = 2.2\text{ k}\Omega$ and $C = 2.2\text{ }\mu\text{F}$. **Boldface** limits apply at the temperature extremes.

Symbol	Parameter	Conditions	Min ⁽²⁾	Typ ⁽³⁾	Max ⁽²⁾	Units	
I_{DD}	Supply Current	$V_{IN} = \text{GND}$	LMV1012-07		158	250 300	μA
			LMV1012-15		200	300 325	
			LMV1012-20		188	260 310	
			LMV1012-25		160	250 300	
SNR	Signal to Noise Ratio	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$, A-Weighted	LMV1012-07		59		dB
			LMV1012-15		60		
			LMV1012-20		61		
			LMV1012-25		61		
V_{IN}	Max Input Signal	$f = 1\text{ kHz}$ and THD+N < 1%	LMV1012-07		170		mV_{PP}
			LMV1012-15		100		
			LMV1012-20		55		
			LMV1012-25		28		
V_{OUT}	Output Voltage	$V_{IN} = \text{GND}$	LMV1012-07	4.45 4.38	4.65	4.80 4.85	V
			LMV1012-15	4.34 4.28	4.56	4.74 4.80	
			LMV1012-20	4.40 4.30	4.58	4.75 4.85	
			LMV1012-25	4.45 4.39	4.65	4.83 4.86	
f_{LOW}	Lower -3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$		67		Hz	
f_{HIGH}	Upper -3dB Roll Off Frequency	$R_{SOURCE} = 50\Omega$		150		kHz	
e_n	Output Noise	A-Weighted	LMV1012-07		-96		dBV
			LMV1012-15		-89		
			LMV1012-20		-84		
			LMV1012-25		-82		
THD	Total Harmonic Distortion	$f = 1\text{ kHz}$, $V_{IN} = 18\text{ mV}$	LMV1012-07		0.12		%
			LMV1012-15		0.13		
			LMV1012-20		0.18		
			LMV1012-25		0.21		
C_{IN}	Input Capacitance			2		pF	
Z_{IN}	Input Impedance			>1000		G Ω	
A_V	Gain	$f = 1\text{ kHz}$, $R_{SOURCE} = 50\Omega$	LMV1012-07	6.4 5.5	8.1	9.5 10.7	dB
			LMV1012-15	14.0 13.1	15.6	16.9 17.5	
			LMV1012-20	19.2 17.0	21.1	22.3 23.5	
			LMV1012-25	22.5 21.2	23.9	25.0 25.8	

- (1) Electrical Table values apply only for factory testing conditions at the temperature indicated. Factory testing conditions result in very limited self-heating of the device such that $T_J = T_A$. No guarantee of parametric performance is indicated in the electrical tables under conditions of internal self-heating where $T_J > T_A$.
- (2) All limits are guaranteed by design or statistical analysis.
- (3) Typical values represent the most likely parametric norm.

Connection Diagram

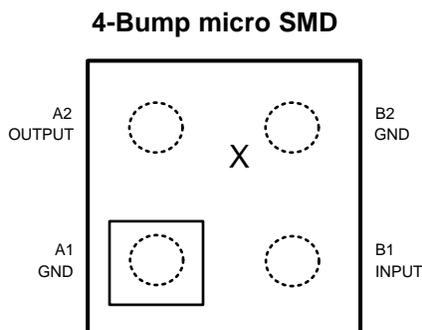


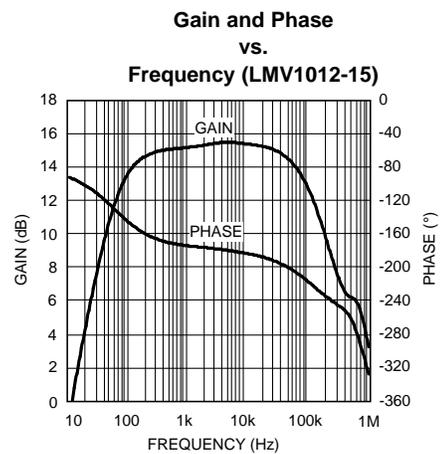
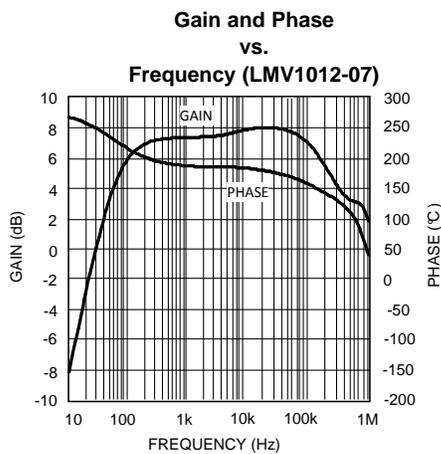
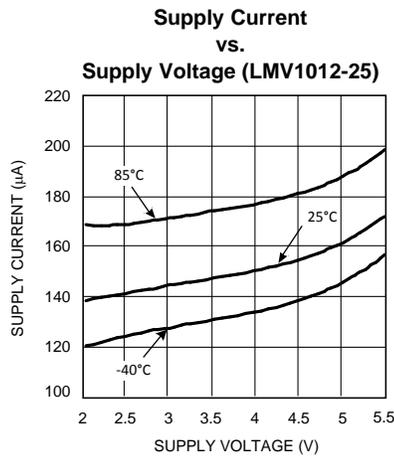
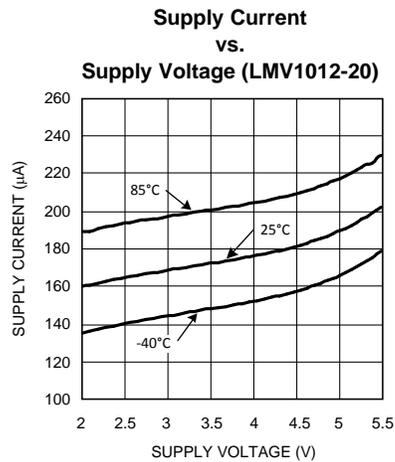
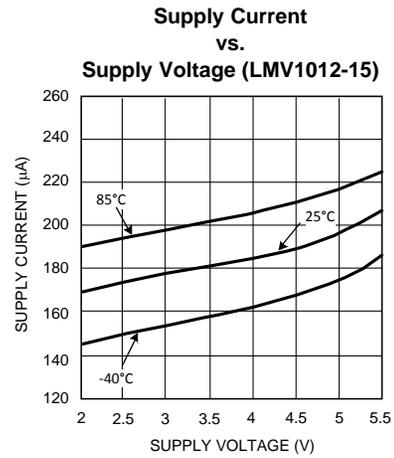
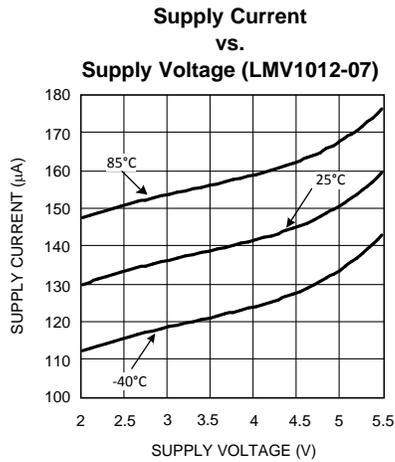
Figure 1. Top View

NOTE

- Pin numbers are referenced to package marking text orientation.
- The actual physical placement of the package marking will vary slightly from part to part. The package will designate the date code and will vary considerably. Package marking does not correlate to device type in any way.

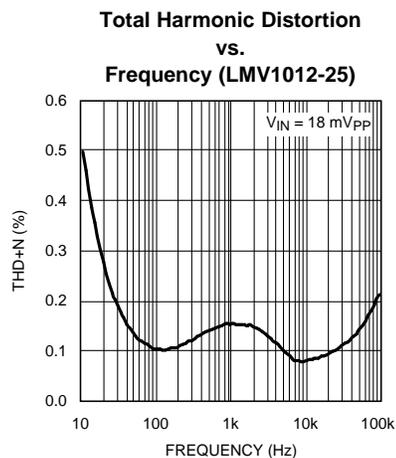
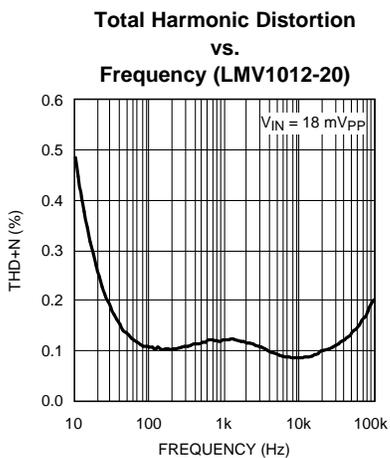
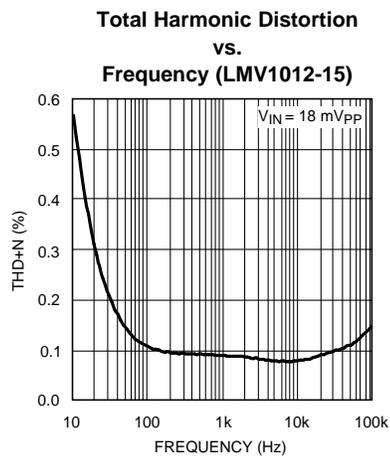
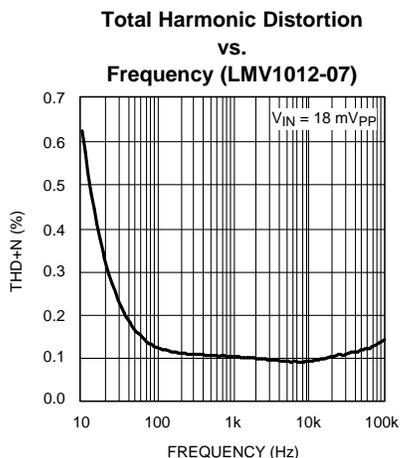
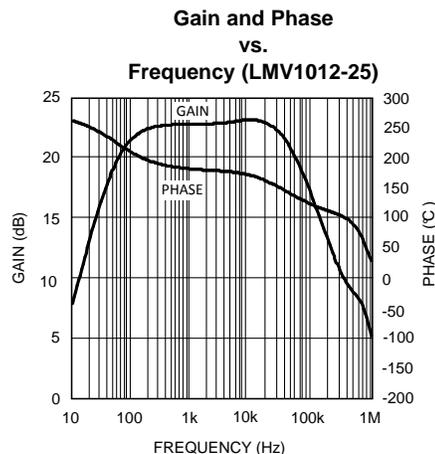
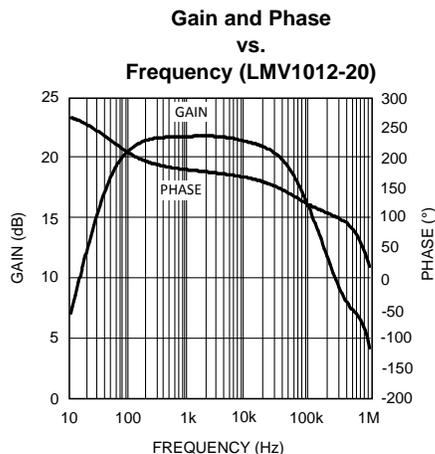
Typical Performance Characteristics

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$



Typical Performance Characteristics (continued)

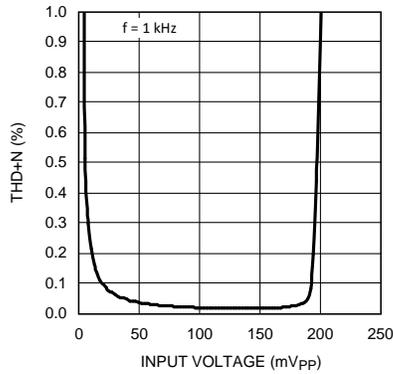
Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$



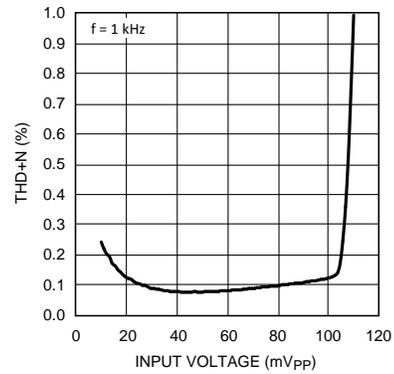
Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$

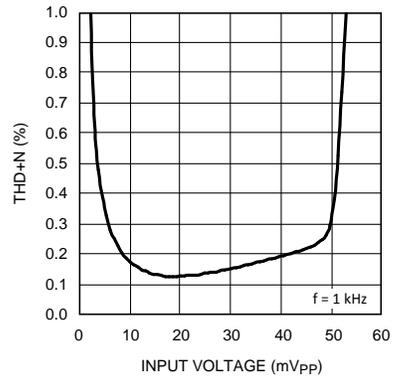
Total Harmonic Distortion vs. Input Voltage (LMV1012-07)



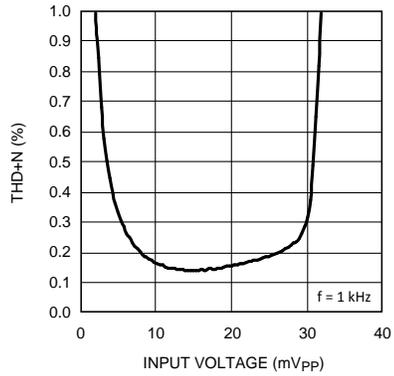
Total Harmonic Distortion vs. Input Voltage (LMV1012-15)



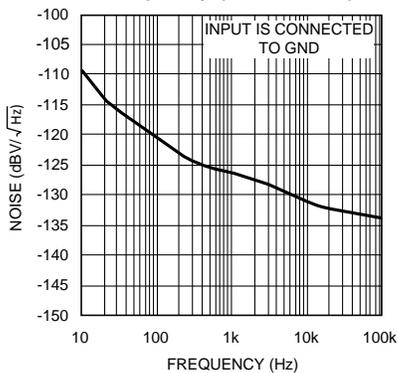
Total Harmonic Distortion vs. Input Voltage (LMV1012-20)



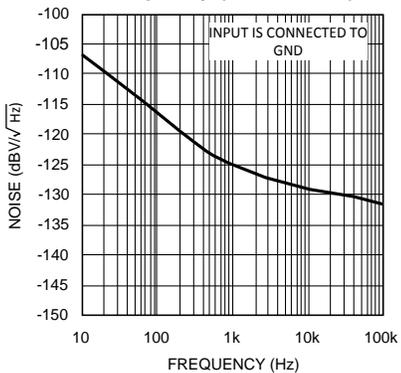
Total Harmonic Distortion vs. Input Voltage (LMV1012-25)



Output Noise vs. Frequency (LMV1012-07)

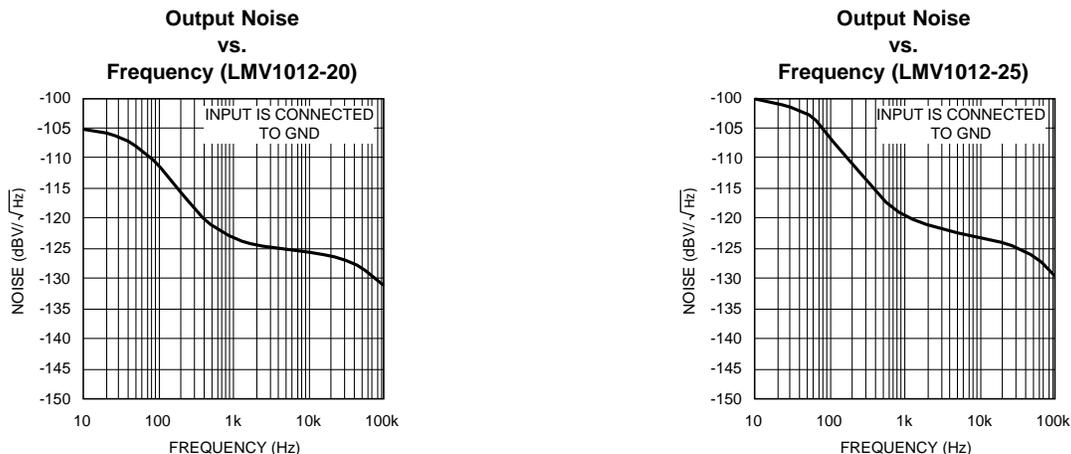


Output Noise vs. Frequency (LMV1012-15)



Typical Performance Characteristics (continued)

Unless otherwise specified, $V_S = 2.2V$, $R_L = 2.2\text{ k}\Omega$, $C = 2.2\text{ }\mu\text{F}$, single supply, $T_A = 25^\circ\text{C}$



Application Section

HIGH GAIN

The LMV1012 series provides outstanding gain versus the JFET and still maintains the same ease of implementation, with improved gain, linearity and temperature stability. A high gain eliminates the need for extra external components.

BUILT IN GAIN

The LMV1012 is offered in 0.3 mm height space saving small 4-pin micro SMD packages in order to fit inside the different size ECM canisters of a microphone. The LMV1012 is placed on the PCB inside the microphone.

The bottom side of the PCB usually shows a bull's eye pattern where the outer ring, which is shorted to the metal can, should be connected to the ground. The center dot on the PCB is connected to the V_{DD} through a resistor. This phantom biasing allows both supply voltage and output signal on one connection.

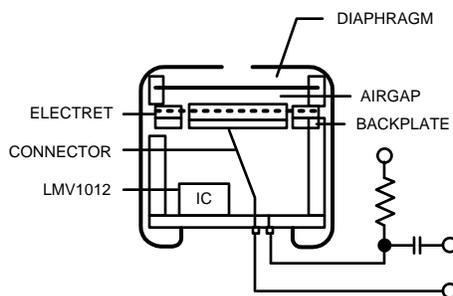


Figure 2. Built in Gain

A-WEIGHTED FILTER

The human ear has a frequency range from 20 Hz to about 20 kHz. Within this range the sensitivity of the human ear is not equal for each frequency. To approach the hearing response weighting filters are introduced. One of those filters is the A-weighted filter.

The A-weighted filter is usually used in signal to noise ratio measurements, where sound is compared to device noise. This filter improves the correlation of the measured data to the signal to noise ratio perceived by the human ear.

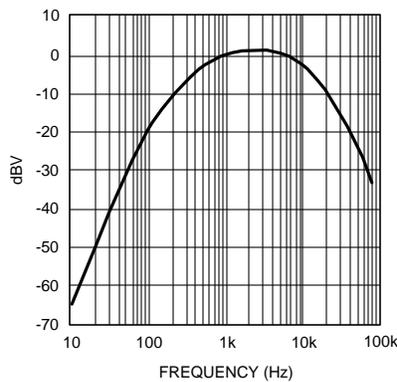


Figure 3. A-Weighted Filter

MEASURING NOISE AND SNR

The overall noise of the LMV1012 is measured within the frequency band from 10 Hz to 22 kHz using an A-weighted filter. The input of the LMV1012 is connected to ground with a 5 pF capacitor, as in [Figure 4](#). Special precautions in the internal structure of the LMV1012 have been taken to reduce the noise on the output.

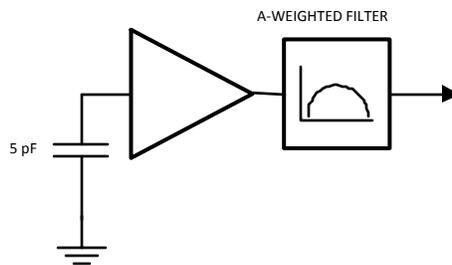


Figure 4. Noise Measurement Setup

The signal to noise ratio (SNR) is measured with a 1 kHz input signal of 18 mV_{pp} using an A-weighted filter. This represents a sound pressure level of 94 dB SPL. No input capacitor is connected for the measurement.

SOUND PRESSURE LEVEL

The volume of sound applied to a microphone is usually stated as a pressure level referred to the threshold of hearing of the human ear. The sound pressure level (SPL) in decibels is defined by:

$$\text{Sound pressure level (dB)} = 20 \log P_m/P_O$$

Where,

P_m is the measured sound pressure

P_O is the threshold of hearing (20 μ Pa)

In order to be able to calculate the resulting output voltage of the microphone for a given SPL, the sound pressure in dB SPL needs to be converted to the absolute sound pressure in dBPa. This is the sound pressure level in decibels referred to 1 Pascal (Pa).

The conversion is given by:

$$\text{dBPa} = \text{dB SPL} + 20 \cdot \log 20 \mu\text{Pa}$$

$$\text{dBPa} = \text{dB SPL} - 94 \text{ dB}$$

Translation from absolute sound pressure level to a voltage is specified by the sensitivity of the microphone. A conventional microphone has a sensitivity of -44 dBV/Pa.

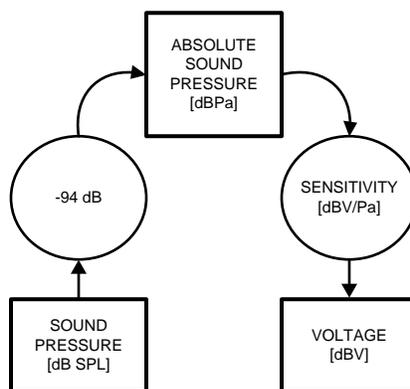


Figure 5. dB SPL to dBV Conversion

Example: Busy traffic is 70 dB SPL

$$V_{OUT} = 70 - 94 - 44 = -68 \text{ dBV}$$

This is equivalent to 1.13 mV_{PP}

Since the LMV1012-15 has a gain of 6 (15.6 dB) over the JFET, the output voltage of the microphone is 6.78 mV_{PP}. By implementing the LMV1012-15, the sensitivity of the microphone is -28.4 dBV/Pa (-44 + 15.6).

LOW FREQUENCY CUT OFF FILTER

To reduce noise on the output of the microphone a low frequency cut off filter has been implemented. This filter reduces the effect of wind and handling noise.

It's also helpful to reduce the proximity effect in directional microphones. This effect occurs when the sound source is very close to the microphone. The lower frequencies are amplified which gives a bass sound. This amplification can cause an overload, which results in a distortion of the signal.

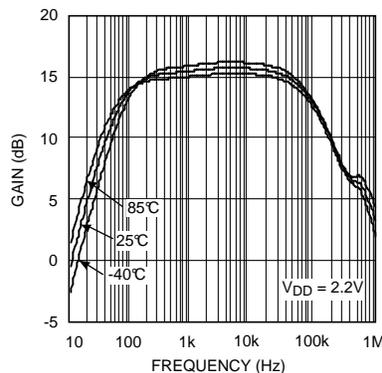


Figure 6. LMV1012-15 Gain vs. Frequency Over Temperature

The LMV1012 is optimized to be used in audio band applications. By using the LMV1012, the gain response is flat within the audio band and has linearity and temperature stability [Figure 6](#).

NOISE

Noise pick-up by a microphone in cell phones is a well-known problem. A conventional JFET circuit is sensitive for noise pick-up because of its high output impedance, which is usually around 2.2 kΩ.

RF noise is amongst other caused by non-linear behavior. The non-linear behavior of the amplifier at high frequencies, well above the usable bandwidth of the device, causes AM-demodulation of high frequency signals. The AM modulation contained in such signals folds back into the audio band, thereby disturbing the intended microphone signal. The GSM signal of a cell phone is such an AM-modulated signal. The modulation frequency of 216 Hz and its harmonics can be observed in the audio band. This kind of noise is called bumblebee noise.

RF noise caused by a GSM signal can be reduced by connecting two external capacitors to ground, see [Figure 7](#). One capacitor reduces the noise caused by the 900 MHz carrier and the other reduces the noise caused by 1800/1900 MHz.

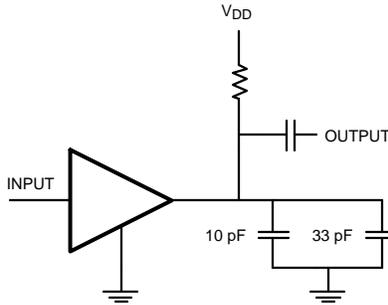


Figure 7. RF Noise Reduction

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)	Op Temp (°C)	Top-Side Markings (4)	Samples
LMV1012TP-07/NOPB	ACTIVE	DSBGA	YPB	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012TP-15/NOPB	ACTIVE	DSBGA	YPB	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012TP-25/NOPB	ACTIVE	DSBGA	YPB	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012TPX-15/NOPB	ACTIVE	DSBGA	YPB	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1012TPX-25/NOPB	ACTIVE	DSBGA	YPB	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1012UP-07/NOPB	ACTIVE	DSBGA	YPC	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UP-15/NOPB	ACTIVE	DSBGA	YPC	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UP-20/NOPB	ACTIVE	DSBGA	YPC	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UP-25/NOPB	ACTIVE	DSBGA	YPC	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UPX-07/NOPB	ACTIVE	DSBGA	YPC	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1012UPX-15/NOPB	ACTIVE	DSBGA	YPC	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UPX-20/NOPB	ACTIVE	DSBGA	YPC	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012UPX-25/NOPB	ACTIVE	DSBGA	YPC	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1012XP-15/NOPB	ACTIVE	DSBGA	YPE	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012XP-25/NOPB	ACTIVE	DSBGA	YPE	4	250	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM			Samples
LMV1012XPX-15/NOPB	ACTIVE	DSBGA	YPE	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples
LMV1012XPX-25/NOPB	ACTIVE	DSBGA	YPE	4	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85		Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Only one of markings shown within the brackets will appear on the physical device.

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TAPE AND REEL INFORMATION



QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

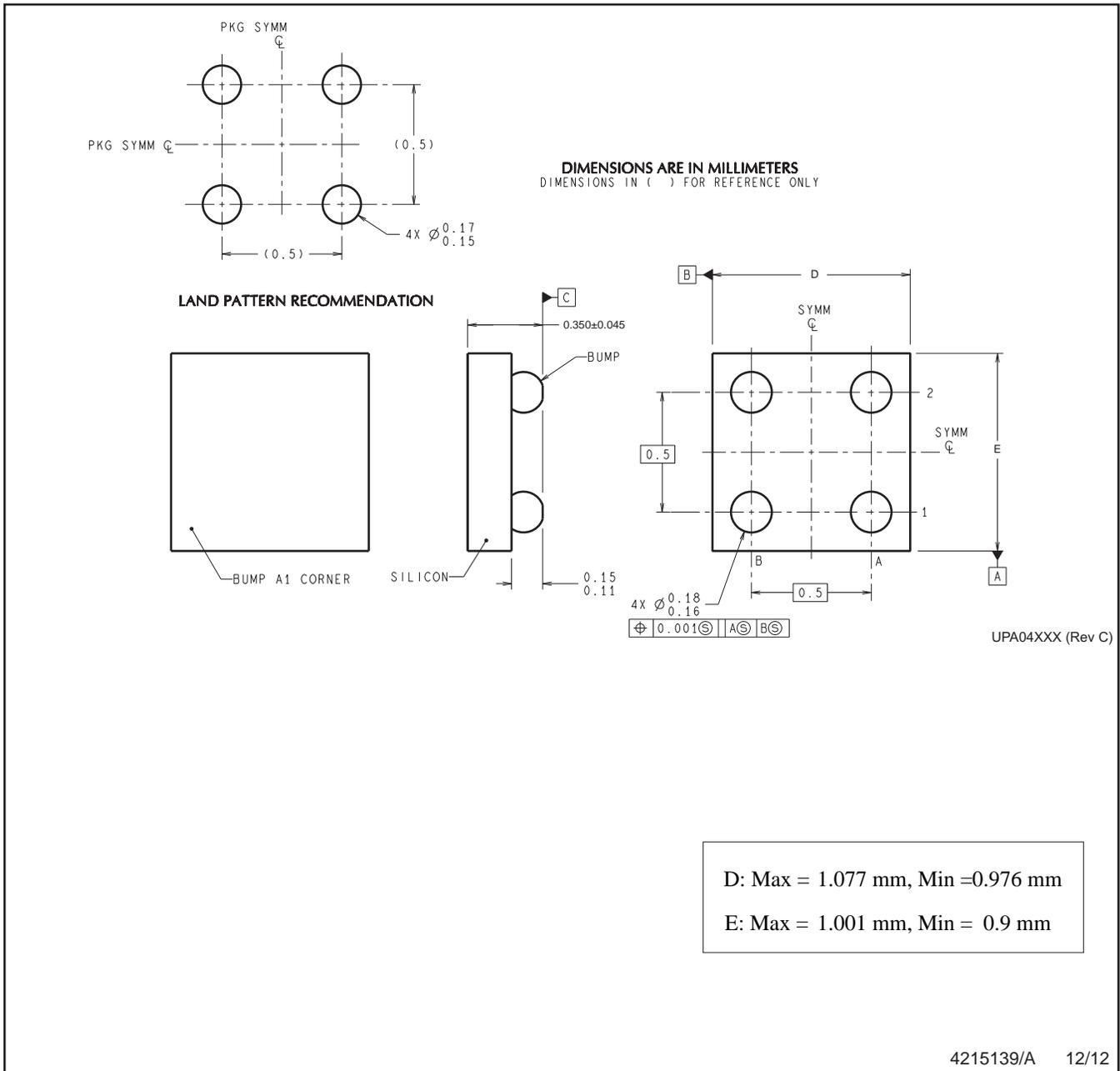
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMV1012TPX-15/NOPB	DSBGA	YPB	4	3000	178.0	8.4	1.02	1.09	0.66	4.0	8.0	Q1
LMV1012TPX-25/NOPB	DSBGA	YPB	4	3000	178.0	8.4	1.02	1.09	0.66	4.0	8.0	Q1
LMV1012XP-15/NOPB	DSBGA	YPE	4	250	178.0	8.4	1.06	1.13	0.4	4.0	8.0	Q1
LMV1012XP-25/NOPB	DSBGA	YPE	4	250	178.0	8.4	1.06	1.13	0.4	4.0	8.0	Q1
LMV1012XPX-15/NOPB	DSBGA	YPE	4	3000	178.0	8.4	1.06	1.13	0.4	4.0	8.0	Q1
LMV1012XPX-25/NOPB	DSBGA	YPE	4	3000	178.0	8.4	1.06	1.13	0.4	4.0	8.0	Q1

TAPE AND REEL BOX DIMENSIONS


*All dimensions are nominal

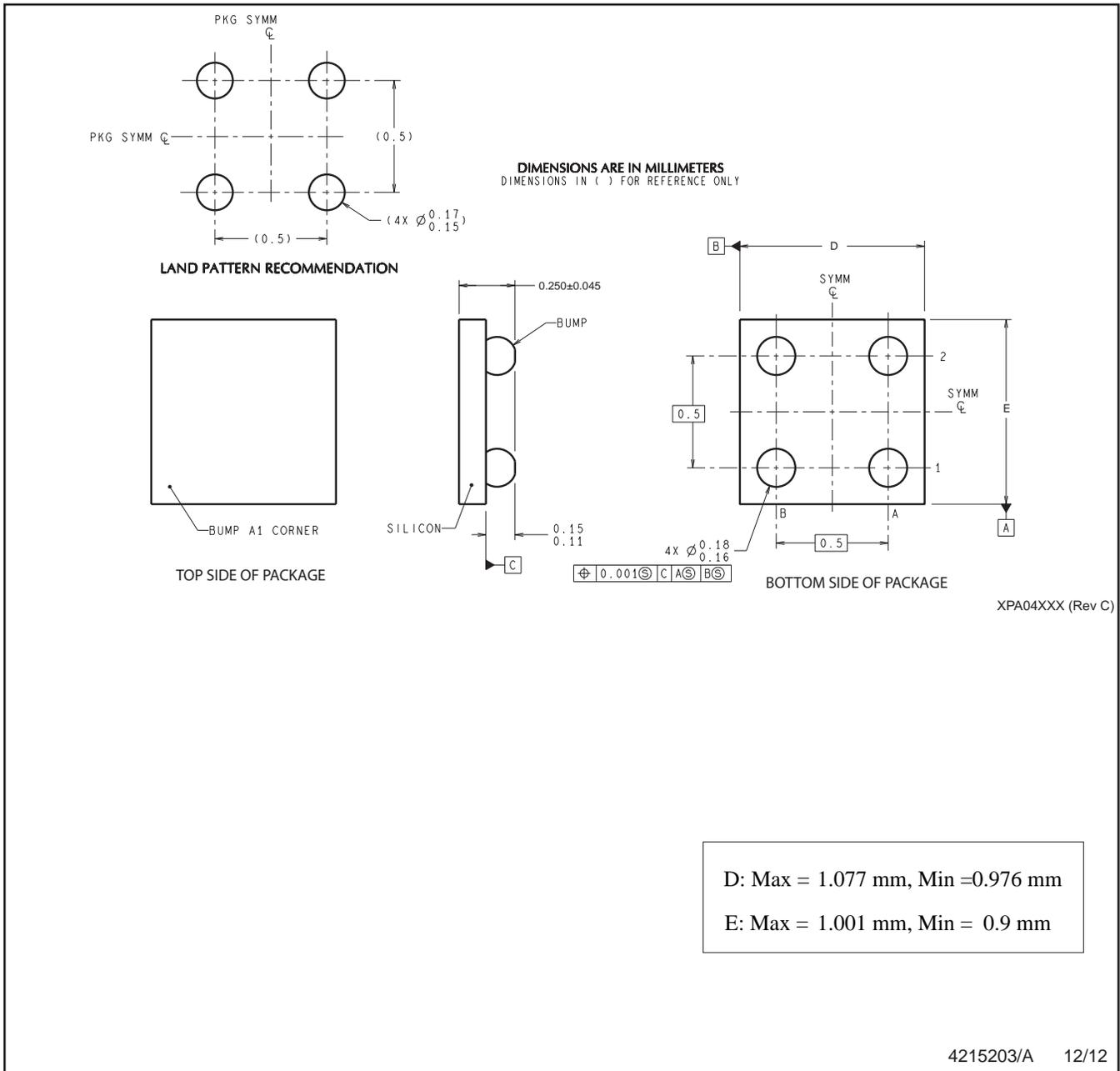
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMV1012TPX-15/NOPB	DSBGA	YPB	4	3000	206.0	191.0	90.0
LMV1012TPX-25/NOPB	DSBGA	YPB	4	3000	206.0	191.0	90.0
LMV1012XP-15/NOPB	DSBGA	YPE	4	250	203.0	190.0	41.0
LMV1012XP-25/NOPB	DSBGA	YPE	4	250	203.0	190.0	41.0
LMV1012XPX-15/NOPB	DSBGA	YPE	4	3000	206.0	191.0	90.0
LMV1012XPX-25/NOPB	DSBGA	YPE	4	3000	206.0	191.0	90.0

YPC0004



NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

YPE0004



D: Max = 1.077 mm, Min = 0.976 mm
E: Max = 1.001 mm, Min = 0.9 mm

4215203/A 12/12

NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

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